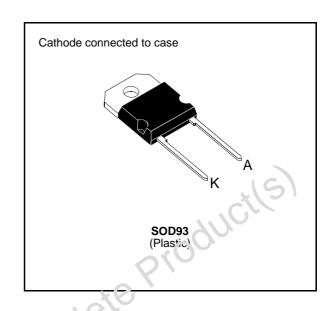


## FAST RECOVERY RECTIFIER DIODES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING



#### **SUITABLE APPLICATIONS**

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

## **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	5	Value	Unit
I <sub>FRM</sub>	Repetive Peak Forward Current	ւ <sub>p</sub> ≤ 10μs	500	Α
I <sub>F (RMS)</sub>	RMS Forward Current		50	А
I <sub>F (AV)</sub>	Average Forward Current	$T_c = 100$ °C $\delta = 0.5$	30	Α
I <sub>FSM</sub>	Surge non Repetiti 'e Fo ward Current	t <sub>p</sub> = 10ms Sinusoidal	350	А
Р	Power Diesipalich	T <sub>c</sub> = 100°C	50	W
T <sub>stg</sub> T <sub>j</sub>	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150	°C

Syn bol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	400	V
V <sub>RSM</sub>	Non Repetitive Peak Reverse Voltage	440	V

#### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R <sub>th (j - c)</sub>	Junction-case	1	°C/W

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#### **ELECTRICAL CHARACTERISTICS**

#### STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I <sub>R</sub>	T <sub>j</sub> = 25°C	$V_R = V_{RRM}$			35	μΑ
	T <sub>j</sub> = 100°C				6	mA
V <sub>F</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 30A			1.5	V
	T <sub>j</sub> = 100°C				1.4	

#### RECOVERY CHARACTERISTICS

Symbol		Te	Min.	Тур.	Max.	Unit		
t <sub>rr</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 1A	$di_F/dt = -15A/\mu s$	$V_R = 30V$			100	ns
		I <sub>F</sub> = 0.5A	I <sub>R</sub> = 1A	$I_{rr} = 0.25A$			50	

## TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Tes	Min.	Тур.	Max.	Unit	
t <sub>IRM</sub>	di <sub>F</sub> /dt = - 120A/μs	V <sub>CC</sub> = 200 V I <sub>F</sub> = 30A			75	ns
	di <sub>F</sub> /dt = - 240A/μs	$L_p \le 0.05 \mu H$ $T_j = 100^{\circ} C$ See figure 11		50		
I <sub>RM</sub>	di <sub>F</sub> /dt = -120A/μs				9	Α
	di <sub>F</sub> /dt = - 240A/μs			12		

## TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Conditions	Min.	Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		3.3		

To evaluate the conduction losses use the following equations:

 $V_F = 1.1 + 0.0095 I_F$   $P = 1.1 \times I_{F(AV)} + 0.0095 I_F^2(RMS)$ 

Figure 1. Low frequency power losses versus average current

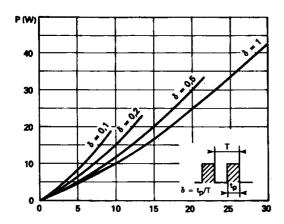


Figure 2. Peak current versus form factor

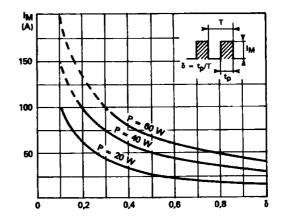


Figure 3. Non repetitive peak surge current versus overload duration

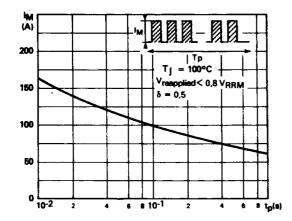


Figure 4. Thermal impedance versus pulse width

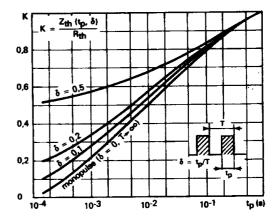


Figure 5. Voltage drop versus forward current

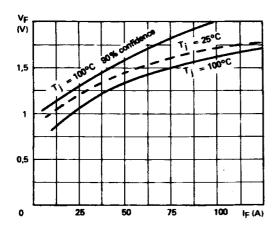


Figure 6. Recovery charge versus di<sub>F</sub>/d<sub>t</sub>-

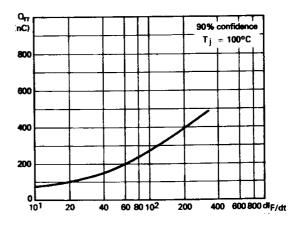


Figure 7. Recovery time versus di<sub>F</sub>/d<sub>t-</sub>

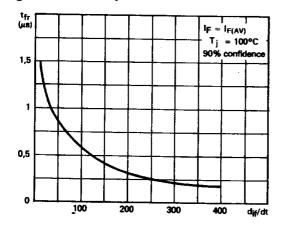
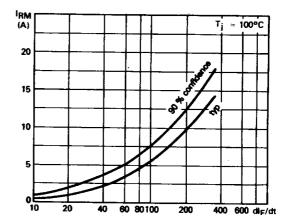


Figure 8. Peak reverse current versus di<sub>F</sub>/d<sub>t</sub>-



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Figure 9. Peak forward voltage versus dir/dt-

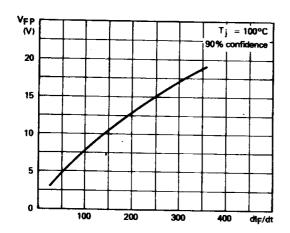


Figure 10. Dynamic parameters versus junction temperature.

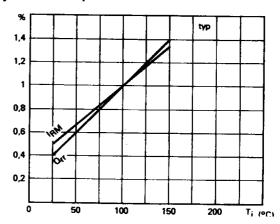


Figure 11. Turn-off switching characteristics (without series inductance).

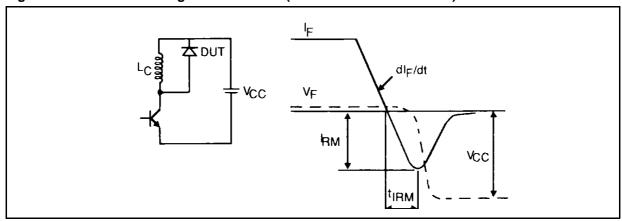
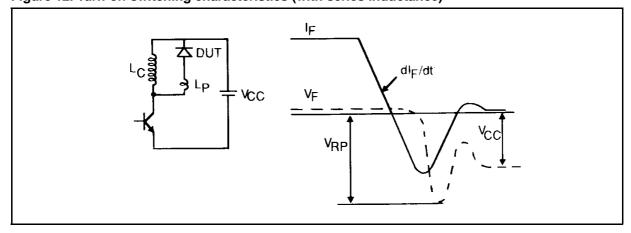


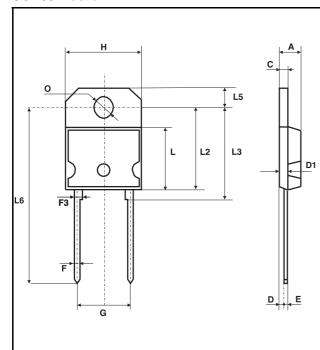
Figure 12. Turn-off switching characteristics (with series inductance)



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#### **PACKAGE MECHANICAL DATA:**

SOD93 Plastic



REF.	DIMENSIONS						
	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.70		4.90	0.185		0.193	
С	1.17		1.37	0.046		0.054	
D		2.50			0.098		
D1		1.27			0.050		
Е	0.50		0.78	0.020		0.031	
F	1.10		1.30	0.043		0.051	
F3		1.75			0.069		
G	10.80		11.10	0.425		0.437	
Н	14.70		15.20	0.578		0.598	
L			12.20			0.480	
L2			16.20			0.638	
L3		18.0			0.709		
L5	3.95		4.15	0.156		0.163	
L6		31.00			1.220		
0	4.00		4.10	0.157		0.161	

■ Marking: type number

■ Cooling method: by conduction (method C)

■ Weight: 3.79g

Recommended torque value: 80cm. NMaximum torque value: 100cm. N

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